DR-DG-40-MO-BB 40 Gbps NRZ / RZ Medium Output Voltage Driver Module



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Features

- Output voltage 6.3 V
- Flat gain up to 40 GHz
- Single voltage power supply
- Gain and crossing point adjustment

Applications

- LiNbO₃ & InP modulators
- 40 Gbps 44 Gbps NRZ / RZ
- SONET OC-768 / SDH-256
- Research & Development

Options

- Heat-sink
- Alternative RF connectors gender
- GPPO connectors
- Low output version for EAM

PRELIMINARY

Digital Driver

The DR-DG-40-MO-BB is a driver module optimized for digital applications at 40 Gbps – 44 Gbps data rate. It exhibits an output voltage of 6.3 V_{pp} and a broad bandwidth of 40 GHz.

The DR-DG-40-MO-BB is housed in a compact package that integrates voltage regulators allowing for flexible biasing, while internal bias sequencing circuitry assures robust operation and single voltage power supply for maximum ease of use. It features two control inputs : one for gain control, the second one for crossing point adjustment. The RF connectors are V type, allowing easy and repeatable connections.

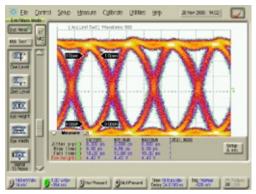
The DR-DG-40-MO-BB combines high performance and user friendliness, it is the ideal device to drive 40 Gbps modulators and to obtain widely opened optical eye diagrams with short jitter and high SNR.

Performance Highlights

| Parameter | Min | Тур | Max | Unit |
|---------------------|------|------|------|-----------------|
| Cut-off frequencies | 50 k | - | 40 G | Hz |
| Output Voltage | - | 6.3 | - | V _{pp} |
| Gain | - | 26 | - | dB |
| Saturated Power | 20 | - | - | dBm |
| Added Jitter | - | 0.42 | - | ps |
| Rise / Fall Times | - | 8 | 12 | ps |

Measurements for V $_{\rm bias}$ = 8 V, V $_{\rm amp}$ = 1.5 V, V $_{\rm xp}$ = 0.8 V, I $_{\rm bias}$ = 300 mA

40 Gbps Output Response



DR-DG-40-MO-BB 40 Gbps NRZ / RZ Medium Output Voltage

Driver Module

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Digital Driver

DC Electrical Characteristics

| Parameter | Symbol | Min | Тур | Мах | Unit |
|-----------------------------|-------------------|-----|-----|-----|------|
| Supply voltage (fixed) | V_{bias} | 7 | 8 | 12 | V |
| Current consumption | I _{bias} | - | 300 | - | mA |
| Gain control voltage | V_{amp} | 0 | 1.5 | 2 | V |
| Cross point control voltage | V _{xp} | 0 | 0.8 | 1.2 | V |

Electrical Characteristics Conditions: V_{in} = 0.65 V_{pp} , T_{amb} = 25 °C, 50 Ω system

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|-----------------------|---------------------------------|--|-----|------|-----|-----------------|
| Lower frequency | f _{3dB} , lower | -3 dB point | - | - | 50 | kHz |
| Upper frequency | f _{3dB} , upper | -3 dB point | 36 | 40 | - | GHz |
| Gain | S ₂₁ | Small signal | - | 26 | - | dB |
| Gain ripple | - | < 40 GHz | - | ±1.5 | - | dB |
| Input return loss | S ₁₁ | 50 MHz < f < 35 GHz | - | -10 | - | dB |
| Output return loss | S ₂₂ | 50 MHz < f < 35 GHz | - | -10 | - | dB |
| Saturated Power | P _{sat} | $V_{in} = 0.65 V_{pp}$ | 20 | - | - | dBm |
| Output voltage | V _{out} | V _{in} = 0.65 V _{pp} | - | 6.3 | 6.5 | V _{pp} |
| Rise time / Fall time | t _r / t _r | 20 % - 80 % | - | 8 | 12 | ps |
| Added jitter | J _{RMS} | J _{RMS} = $\sqrt{J^2_{RMS-total} - J^2_{RMS-source}}$ | - | 0.42 | - | ps |
| Power dissipation | Р | $V_{out} = 6.3 V_{pp}$ | - | 2.4 | - | W |

Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

| Parameter | Symbol | Min | Max | Unit |
|-----------------------------|-------------------|-----|-----|-----------------|
| RF input voltage | V _{in} | - | 1 | V _{pp} |
| Supply voltage | V _{bias} | 0 | 12 | V |
| DC current | I _{bias} | 0 | 330 | mA |
| Gain control voltage | V _{amp} | 0 | 2 | V |
| Cross point control voltage | V _{xp} | 0 | 2.4 | V |
| Power dissipation | P _{diss} | - | 3 | W |
| Temperature of operation | T _{op} | 0 | +50 | W |
| Storage temperature | T _{st} | -10 | +70 | °C |

DR-DG-40-MO-BB

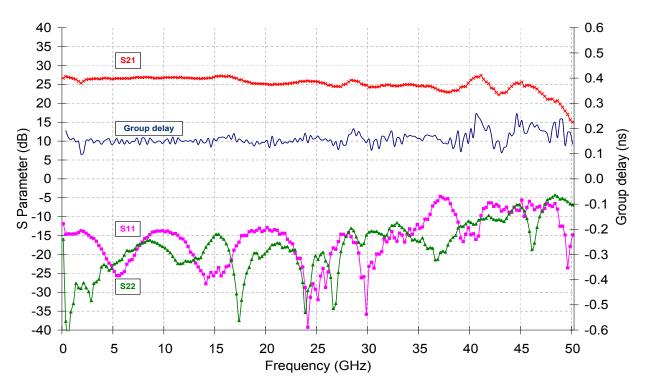


40 Gbps NRZ / RZ Medium Output Voltage Driver Module

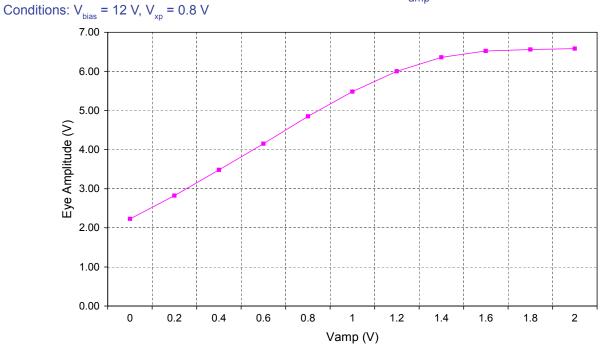
Digital Driver

S parameters curves

Conditions: $V_{\text{bias}} = 12 \text{ V}$, $V_{\text{amp}} = 1.5 \text{ V}$, $V_{\text{xp}} = 0.8 \text{ V}$, $I_{\text{bias}} = 300 \text{ mA}$







DR-DG-40-MO-BB

40 Gbps NRZ / RZ Medium Output Voltage Driver Module

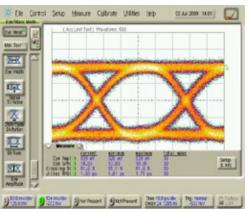


Digital Driver

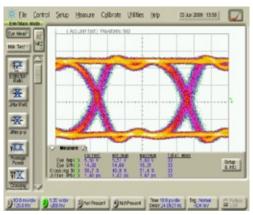
Eye Diagrams

20 Gbps data rate

Conditions: Ratio $\frac{1}{2}$, Pattern 2³¹-1 V_{bias} = 8 V, V_{amp} = 1.5 V, V_{xp} = 0.8 V, I_{bias} = 305 mA



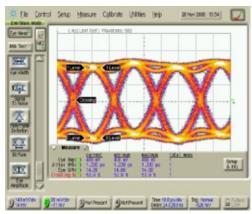
Input signal Generated with a NEL MOF15A 2:1 selector Eye amplitude = 0.53 V_{pp}, Rise time = 20.2 ps Jitter RMS = 1.63 ps, SNR = 10.9



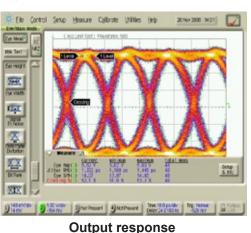
Output response Measured using Agilent 86100B with two 50 GHz 8348A channels module, and without precision time-base module Eye amplitude = 5.58 V_{pp}, Rise time = 9.8 ps Jitter RMS = 1.48 ps, SNR = 14.9

40 Gbps data rate

Conditions: Ratio $\frac{1}{2}$, Pattern 2³¹-1 V_{bias} = 8 V, V_{amp} = 1.5 V, V_{xp} = 0.8 V, I_{bias} = 305 mA



Input signal Generated using Centellax MUX MS4S1V2M 56Gbps 4:1 Eye amplitude = 0.41 V_{pp}, Rise time = 10.2 ps Jitter RMS = 1.23 ps, SNR = 14.7



Measured using Agilent 86100B with two 50 GHz 8348A channels module, and without precision time-base module Eye amplitude = $5.62 V_{pp}$, Rise time = 9.56 psJitter RMS = 1.33 ps, SNR = 14.1

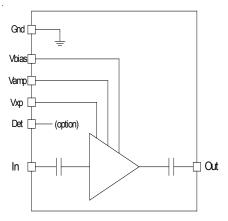
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Driver Module



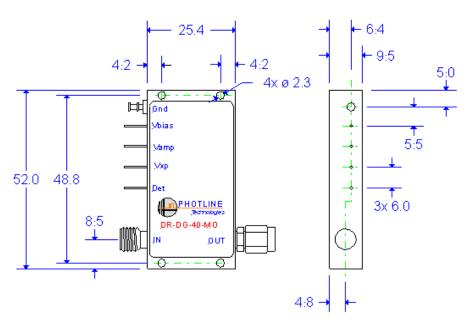
Digital Driver

Electrical Schematic Diagram



Mechanical diagram and pinout

All measurements in mm





The heatsinking of the module is necessary. It's user responsability to use an adequate heatsink. Refer to page 6 for Photline Technologies recommended heatsink.

| PIN | Function | Operational Notes | |
|-------------------|---------------------------------------|--|--|
| IN | RF In | V-connector female | |
| OUT | RF Out | V-connector male | |
| V _{bias} | Power supply voltage | Set at typical operating specification | |
| V _{amp} | Output voltage amplitude adjustment | Adjust for gain control tuning | |
| V _{xp} | Output voltage cross point adjustment | Adjust for cross point control tuning | |

DR-DG-40-MO-BB 40 Gbps NRZ / RZ Medium Output Voltage

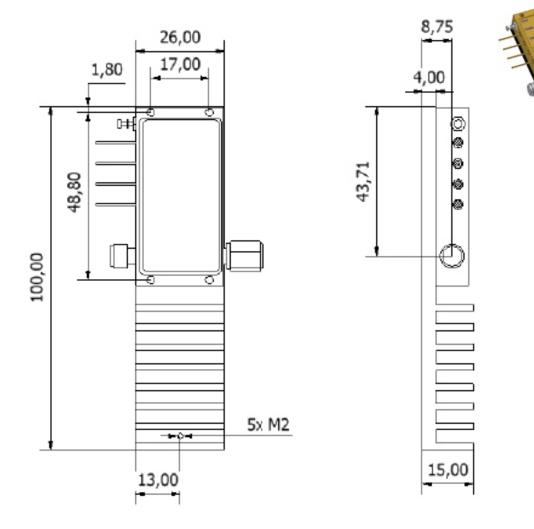
Driver Module



Digital Driver

HS-MO2

Mechanical diagram and pinout with HS-MO2 heatsink All measurements in mm



ABOUT US

Photline Technologies is a provider of Fiber Optics Modulation Solutions based on the company $LiNb0_3$ modulators and high-speed electronics modules. Photline Technologies offers high speed and high data rate modulation solutions for the telecommunication industry and the defense, aerospace, instruments and sensors markets. The products offered by the company include : comprehensive range of intensity and phase modulators (800 nm, 1060 nm, 1300 nm, 1550 nm), RF drivers and modules, transmitters and modulation units.

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